

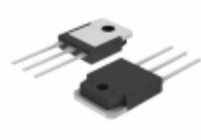
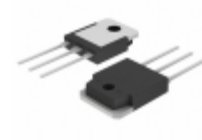
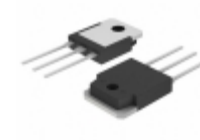
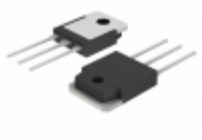
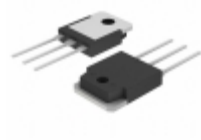
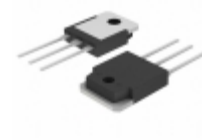
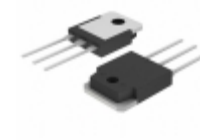
	<p><b>FQA7N80C</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQA7N80C</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 800V 7A TO-3P</p> <p><b>Datenblätter:</b>  <a href="#">FQA7N80C.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 1568 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQA7N80C</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 800V 7A TO-3P
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	1568 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	198W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7A (Tc)
Rds On (Max) @ Id, Vgs	1.9 Ohm @ 3.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1680pF @ 25V
Verpackung	Tube

FQA7N80C ist neu im Original, Suche FQA7N80C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA7N80C Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQA7N80C: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQA7N60</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 7.7A TO-3P</p>	 <p><b>FQA7N80C_F109</b> Fairchild/ON Semiconductor MOSFET N-CH 800V 7A TO-3P</p>	 <p><b>FQA7N80C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 7A TO-3P</p>	 <p><b>FQA7N80C-F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 7A TO-3P</p>
 <p><b>FQA7N80</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 7.2A TO-3P</p>	 <p><b>FQA7N80_F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 7.2A TO-3P</p>	 <p><b>FQA7N60</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.7A TO-3P</p>	 <p><b>FQA7N80</b> Fairchild/ON Semiconductor MOSFET N-CH 800V 7.2A TO-3P</p>

### heiße Teile

Mehr


Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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